

L Number	Hits	Search Text	DB	Time stamp
15	25	(nippondenso\$.as. and ((magneto adj resist\$4) or magnetoresist\$4 or mr or gmr or TMR or (magnetic adj tunnel adj junction))) and insulat\$3	USPAT; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 09:06
16	3	(nippondenso.as. and (shield\$3)) and ((magneto adj resist\$4) or magnetoresist\$4 or mr or gmr or TMR or (magnetic adj tunnel adj junction))	USPAT; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 08:26
17	3	(nippondenso\$.as. and (shield\$3)) and ((magneto adj resist\$4) or magnetoresist\$4 or mr or gmr or TMR or (magnetic adj tunnel adj junction))	USPAT; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 08:26
18	206	(nippondenso\$.as. and ((organic with film) or polyimide or (resist adj film) or benzocyclobutane))	USPAT; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 08:35
19	9	((nippondenso\$.as. and ((organic with film) or polyimide or (resist adj film) or benzocyclobutane)) ) and (shield\$3)	USPAT; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 08:29
20	2	((nippondenso\$.as. and ((organic with film) or polyimide or (resist adj film) or benzocyclobutane)) ) and (reliev\$3 with thermal with stress\$3)	USPAT; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 08:35
21	102	((organic with film) or polymide or (resist adj film) or benzocyclobutene) with film) and (reliev\$3 with thermal with stress)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 09:01
23	12	((magneto adj resist\$4) or MR or GMR or TMR or (magnetic adj tunnel adj junction) or magnetorsist\$4) and (reliev\$3 with thermal with stress)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 09:03
24	52	((nippondenso\$.as. or denso\$.as.) and ((magneto adj resist\$4) or magnetoresist\$4 or mr or gmr or TMR or (magnetic adj tunnel adj junction))) and insulat\$3	USPAT; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 09:07
25	246	((nippondenso\$.as. or denso\$.as.) and ((magneto adj resist\$4) or magnetoresist\$4 or mr or gmr or TMR or (magnetic adj tunnel adj junction)))	USPAT; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 09:08
26	3	((nippondenso\$.as. or denso\$.as.) and ((magneto adj resist\$4) or magnetoresist\$4 or mr or gmr or TMR or (magnetic adj tunnel adj junction))) and (shield\$3)	USPAT; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 09:07
27	6881	((magneto adj resist\$4) or magnetoresist\$4 or mr or gmr or TMR or (magnetic adj tunnel adj junction)) and shield\$3	USPAT; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 09:09
28	3403	((magneto adj resist\$4) or magnetoresist\$4 or mr or gmr or TMR or (magnetic adj tunnel adj junction)) and shield\$3) and insulat\$3	USPAT; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 09:09
29	9962	"29" and (aluminum with wir\$3)	USPAT; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 09:10
30	41	((magneto adj resist\$4) or magnetoresist\$4 or mr or gmr or TMR or (magnetic adj tunnel adj junction)) and shield\$3) and insulat\$3) and (aluminum with wir\$3)	USPAT; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 09:12
31	0	36/324.2.ccls. and shield\$3	USPAT; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 09:12

32	62	360/324.2.ccls. and shield\$3	USPAT; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 09:17
33	0	360/324.2.ccls. and (reliev\$3 with stress)	USPAT; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 09:17
38	41	nickel with iron with "69"	USPAT; EPO; JPO; DERWENT	2003/05/28 11:39
39	144	nickel with iron with insulat\$3 with film	USPAT; EPO; JPO; DERWENT	2003/05/28 11:43
40	174	nickel with iron with shield\$3 with layer	USPAT; EPO; JPO; DERWENT	2003/05/28 14:39
41	45	nickel with iron with shield\$3 with layer	US-PGPUB	2003/05/28 12:02
42	210	nippondenso.as. or denso.as.	US-PGPUB	2003/05/28 12:02
43	0	((nippondenso.as. or denso.as.) and(((magneto adj resist\$4) or magnetoresist\$4 or mr or gmr or TMR or (magnetic adj tunnel adj junction)))	USPAT; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 12:03
44	0	((nippondenso.as. or denso.as.) and (((magneto adj resist\$4) or magnetoresist\$4 or mr or gmr or TMR or (magnetic adj tunnel adj junction)))	USPAT; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 12:03
45	2	((nippondenso.as. or denso.as.) and (((magneto adj resist\$4) or magnetoresist\$4 or mr or gmr or TMR or (magnetic adj tunnel adj junction)))	US-PGPUB	2003/05/28 12:04
46	7669	((((magneto adj resist\$4) or magnetoresist\$4 or mr or gmr or TMR or (magnetic adj tunnel adj junction)))	US-PGPUB	2003/05/28 12:04
47	902	(TMR or (magnetic adj tunnel adj junction))	US-PGPUB	2003/05/28 12:04
48	265	((TMR or (magnetic adj tunnel adj junction))) and shield\$3	US-PGPUB	2003/05/28 12:04
49	20	((((TMR or (magnetic adj tunnel adj junction))) and shield\$3 and serial\$2	US-PGPUB	2003/05/28 12:11
50	1	("54127363").PN.	USPAT; US-PGPUB; JPO; DERWENT	2003/05/28 14:23
54	11	nickel with iron with shield\$3 with "%"	USPAT	2003/05/28 14:41
55	8	(nickel with "%") same shield same iron	USPAT	2003/05/28 14:42
56	24	(nickel with "%") same shield\$3 same iron	USPAT	2003/05/28 14:44
57	64	((nickel or Ni) with "%") same shield\$3 same (iron or Fe)	USPAT	2003/05/28 14:45
58	0	shield with layer with undercut with wall	USPAT	2003/05/28 15:10
59	7	shield with layer with undercut	USPAT	2003/05/28 15:11
60	99	shield with undercut	USPAT	2003/05/28 15:11
-	149	substrate and insulat\$3 and magnetoresist\$4 and ((organic or polyimide or benzocyclobutene) with film) and shield\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/27 08:14
-	119	(substrate with insulat\$3) and magnetoresist\$4 and ((organic or polyimide or benzocyclobutene) with film) and shield\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/22 15:04
-	29	((organic or polyimide or benzocyclobutene) with film) same (reliev\$3 with stress)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/27 08:49
-	0	((organic or polyimide or benzocyclobutene) with film) and (reliev\$3 with stress) and (magnetoreis\$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/22 15:09

-	3	((organic or polyimide or benzocyclobutene) with film) and (reliev\$3 with stress) and (magnetoresist\$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 08:36
-	3351	((Magnetic adj tunnel adj junction) or (MTJ) or TMR)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/27 08:19
-	767	((((Magnetic adj tunnel adj junction) or (MTJ) or TMR)) and substrate and insulat\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/27 08:19
-	312	(((((Magnetic adj tunnel adj junction) or (MTJ) or TMR)) and substrate and insulat\$3) and shield\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/27 08:20
-	75	(((((Magnetic adj tunnel adj junction) or (MTJ) or TMR)) and substrate and insulat\$3) and shield\$3) and (organic or polyamide or (resist adj film) or benzocyclobutene)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/27 08:27
-	132	shield\$3 with cover\$3 with ((magneto adj resist\$4) or magnetoresist\$4 or MR or GMR or TMR or (magnetic adj tunnel adj junctionN))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/05/27 08:35
-	7	((("5062381") or ("1096815")).PN.	USPAT; US-PGPUB; DERWENT; IBM_TDB	2003/05/27 08:38
-	0	((("5062381") or ("1096815")).PN.	JPO	2003/05/27 08:48
-	167	((organic or polyimide or benzocyclobutene)) same (reliev\$3 with stress)	USPAT; EPO; JPO; DERWENT; IBM_TDB	2003/05/27 08:49
-	2	((((organic or polyimide or benzocyclobutene)) same (reliev\$3 with stress) ) and ((magneto adj resist\$4) or magnetoresist\$4 or mr or gmr or TMR or (magnetic adj tunnel adj junction))	USPAT; EPO; JPO; DERWENT; IBM_TDB	2003/05/27 08:51
-	60491	((magneto adj resist\$4) or magnetoresist\$4 or mr or gmr or TMR or (magnetic adj tunnel adj junction))	USPAT; EPO; JPO; DERWENT; IBM_TDB	2003/05/27 09:09
-	101	((((magneto adj resist\$4) or magnetoresist\$4 or mr or gmr or TMR or (magnetic adj tunnel adj junction))) and (shield\$3 same (organic or benzocyclobutane or (resist adj film) or polyimide) same insulat\$3)	USPAT; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 12:03
-	48	((((magneto adj resist\$4) or magnetoresist\$4 or mr or gmr or TMR or (magnetic adj tunnel adj junction))) and (shield\$3 with (organic or benzocyclobutane or (resist adj film) or polyimide) same insulat\$3)	USPAT; EPO; JPO; DERWENT; IBM_TDB	2003/05/27 08:57
-	45	((((magneto adj resist\$4) or magnetoresist\$4 or mr or gmr or TMR or (magnetic adj tunnel adj junction))) and (shield\$3 with (organic or benzocyclobutane or (resist adj film) or polyimide) with insulat\$3)	USPAT; EPO; JPO; DERWENT; IBM_TDB	2003/05/27 09:09
-	48843	denso.as.	USPAT; EPO; JPO; DERWENT; IBM_TDB	2003/05/27 09:09
-	826	denso.as. and (shield\$3)	USPAT; EPO; JPO; DERWENT; IBM_TDB	2003/05/27 09:09

0	(denso.as. and (shield\$3)) and ((magneto adj resist\$4) or magnetoresist\$4 or mr or gmr or TMR or (magnetic adj tunnel adj junction))	USPAT; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 08:25
0	(denso\$.as. and ((magneto adj resist\$4) or magnetoresist\$4 or mr or gmr or TMR or (magnetic adj tunnel adj junction))) and shield\$3	USPAT; EPO; JPO; DERWENT; IBM_TDB	2003/05/27 09:11
27	(denso\$.as. and ((magneto adj resist\$4) or magnetoresist\$4 or mr or gmr or TMR or (magnetic adj tunnel adj junction))) and insulat\$3	USPAT; EPO; JPO; DERWENT; IBM_TDB	2003/05/28 08:21
0	(denso\$.as. and ((magneto adj resist\$4) or magnetoresist\$4 or mr or gmr or TMR or (magnetic adj tunnel adj junction))) and organic	USPAT; EPO; JPO; DERWENT; IBM_TDB	2003/05/27 09:12
1	(denso\$.as. and ((magneto adj resist\$4) or magnetoresist\$4 or mr or gmr or TMR or (magnetic adj tunnel adj junction))) and polyimide	USPAT; EPO; JPO; DERWENT; IBM_TDB	2003/05/27 09:12
112	denso\$.as. and ((magneto adj resist\$4) or magnetoresist\$4 or mr or gmr or TMR or (magnetic adj tunnel adj junction))	USPAT; EPO; JPO; DERWENT; IBM_TDB	2003/05/27 09:19
5	((("5806172") or ("5790353") or ("5471084") or ("6452381") or ("5618738")).PN.	USPAT	2003/05/27 09:23
1	("20030094944").PN.	USPAT; US-PGPUB	2003/05/27 09:23
2520	((324/252,249,207.21) or (438/48,51,99) or (360/319,320,324.2) or (428/692,694sl)).CCLS.	USPAT	2003/05/27 10:26
458	((324/252,249,207.21) or (438/48,51,99) or (360/319,320,324.2) or (428/692,694sl)).CCLS.) and ((organic with film) or polyimide or benzocyclobutane or (resist adj film))	USPAT; US-PGPUB; DERWENT	2003/05/27 10:27
96	((324/252,249,207.21) or (438/48,51,99) or (360/319,320,324.2) or (428/692,694sl)).CCLS.) and ((organic with film) or polyimide or benzocyclobutane or (resist adj film)) and (shield\$3)	USPAT; US-PGPUB; DERWENT	2003/05/27 10:27
33	((324/252,249,207.21) or (438/48,51,99) or (360/319,320,324.2) or (428/692,694sl)).CCLS.) and ((organic with film) or polyimide or benzocyclobutane or (resist adj film)) and (shield\$3) and (insulat\$3 with substrate)	USPAT; US-PGPUB; DERWENT	2003/05/27 10:27